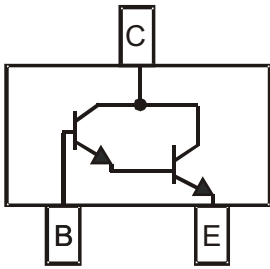


BCV27 BCV47 NPN Darlington Transistor

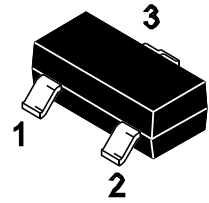
Features

- High Collector Current
- High Current Gain

Equivalent Circuit



SOT-23



1.Base 2.Emitter 3.Collector

Marking Code:

BCV27 : FF

BCV47 : FH

Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

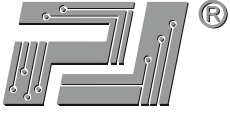
Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	BCV27 40	V
BCV47 80			
Collector Emitter Voltage	V_{CEO}	BCV27 30	V
BCV47 60			
Emitter Base Voltage	V_{EBO}	10	V
Collector Current	I_C	500	mA
Peak Collector Current	I_{CM}	800	mA
Base Current	I_B	100	mA
Maximum Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-65 to +150	°C



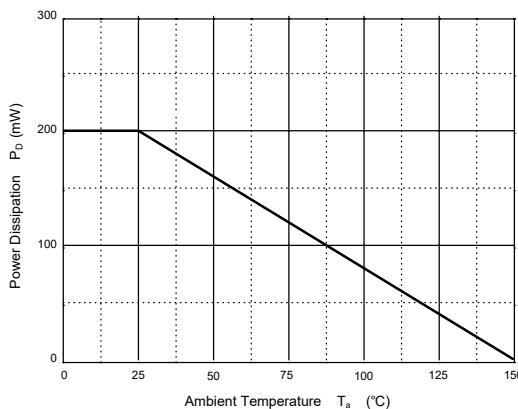
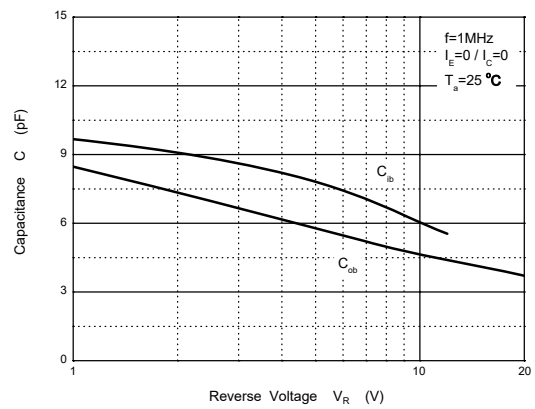
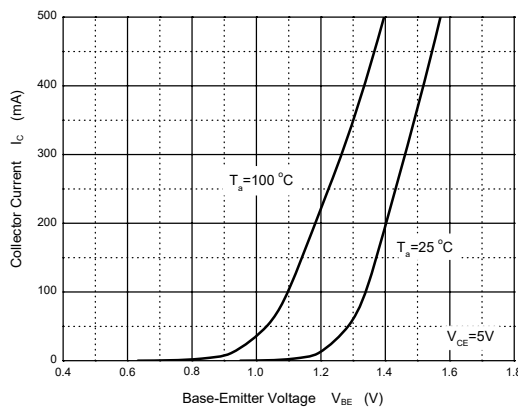
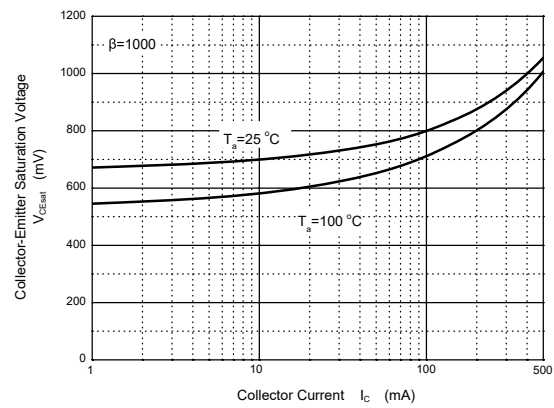
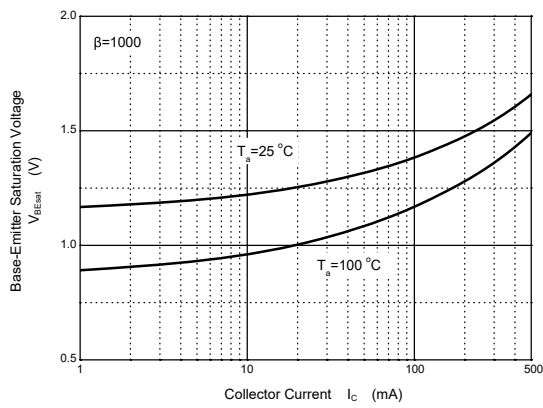
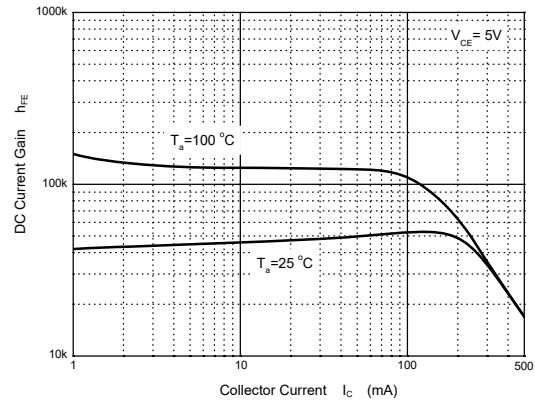
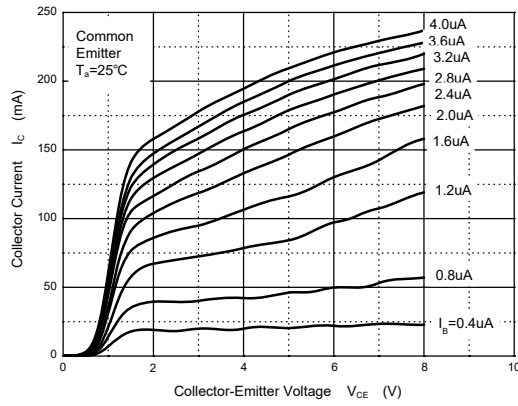
Electrical Characteristics

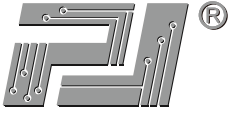
Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain					
at $V_{CE} = 5\text{ V}$, $I_C = 1\text{ mA}$	BCV27	4000	--	--	
	BCV47	2000	--	--	
at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$	BCV27	10000	--	--	--
	BCV47	4000	--	--	
at $V_{CE} = 5\text{ V}$, $I_C = 100\text{ mA}$	BCV27	20000	--	--	
	BCV47	10000	--	--	
Collector Base Cutoff Current					
at $V_{CB} = 30\text{ V}$	BCV27	--	--	100	nA
at $V_{CB} = 60\text{ V}$	BCV47	--	--	100	
Emitter Base Cutoff Current					
at $V_{EB} = 10\text{ V}$		--	--	100	nA
Collector Base Breakdown Voltage					
at $I_C = 100\text{ }\mu\text{A}$	BCV27	40	--	--	V
	BCV47	80	--	--	
Collector Emitter Breakdown Voltage					
at $I_C = 10\text{ mA}$	BCV27	30	--	--	V
	BCV47	60	--	--	
Emitter Base Breakdown Voltage					
at $I_E = 10\text{ }\mu\text{A}$		10	--	--	V
Collector Emitter Saturation Voltage					
at $I_C = 100\text{ mA}$, $I_B = 0.1\text{ mA}$		--	--	1	V
Base Emitter Saturation Voltage					
at $I_C = 100\text{ mA}$, $I_B = 0.1\text{ mA}$		--	--	1.5	V
Base Emitter On Voltage					
at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$		--	--	1.4	V
Transition Frequency					
at $V_{CE} = 5\text{ V}$, $I_C = 30\text{ mA}$, $f = 100\text{ MHz}$	F_T	--	220	--	MHz



Typical Characteristic Curves





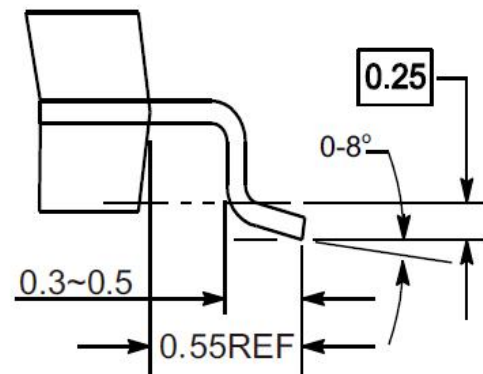
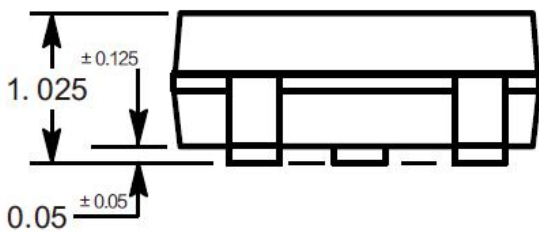
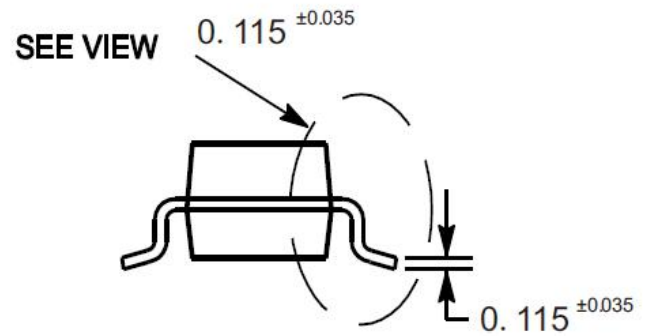
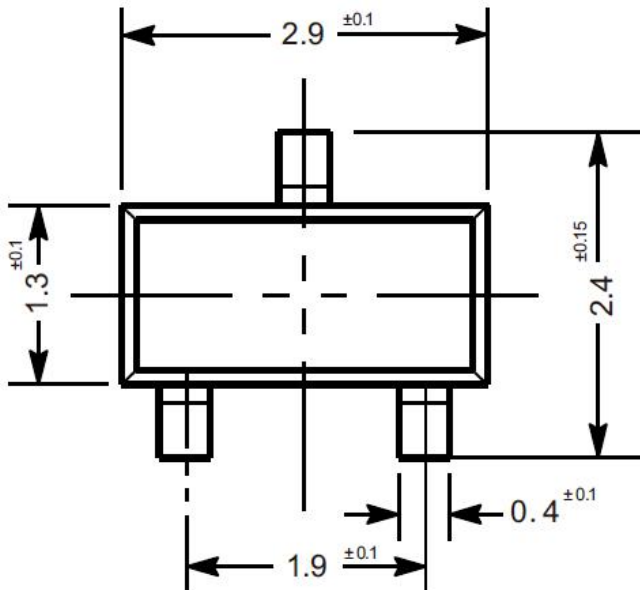
BCV27
BCV47

NPN Darlington Transistor

Package Outline

SOT-23

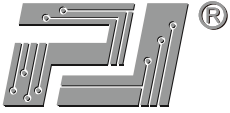
Dimensions in mm



VIEW C

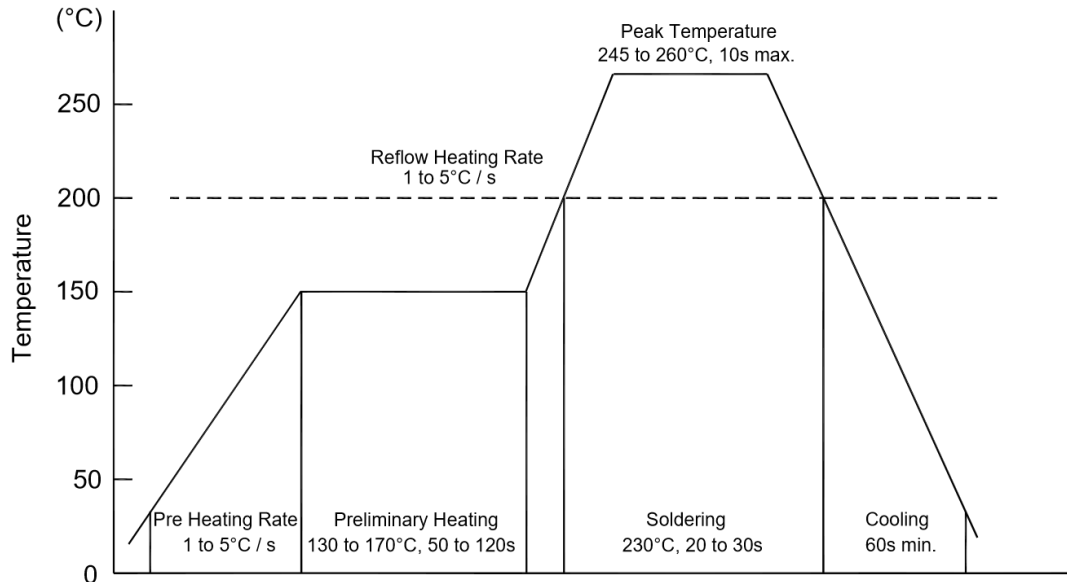
Ordering Information

Device	Package	Shipping
BCV27,BCV47	SOT-23	3,000PCS/Reel&7inches



Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

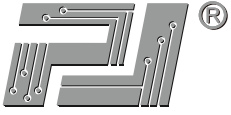
- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

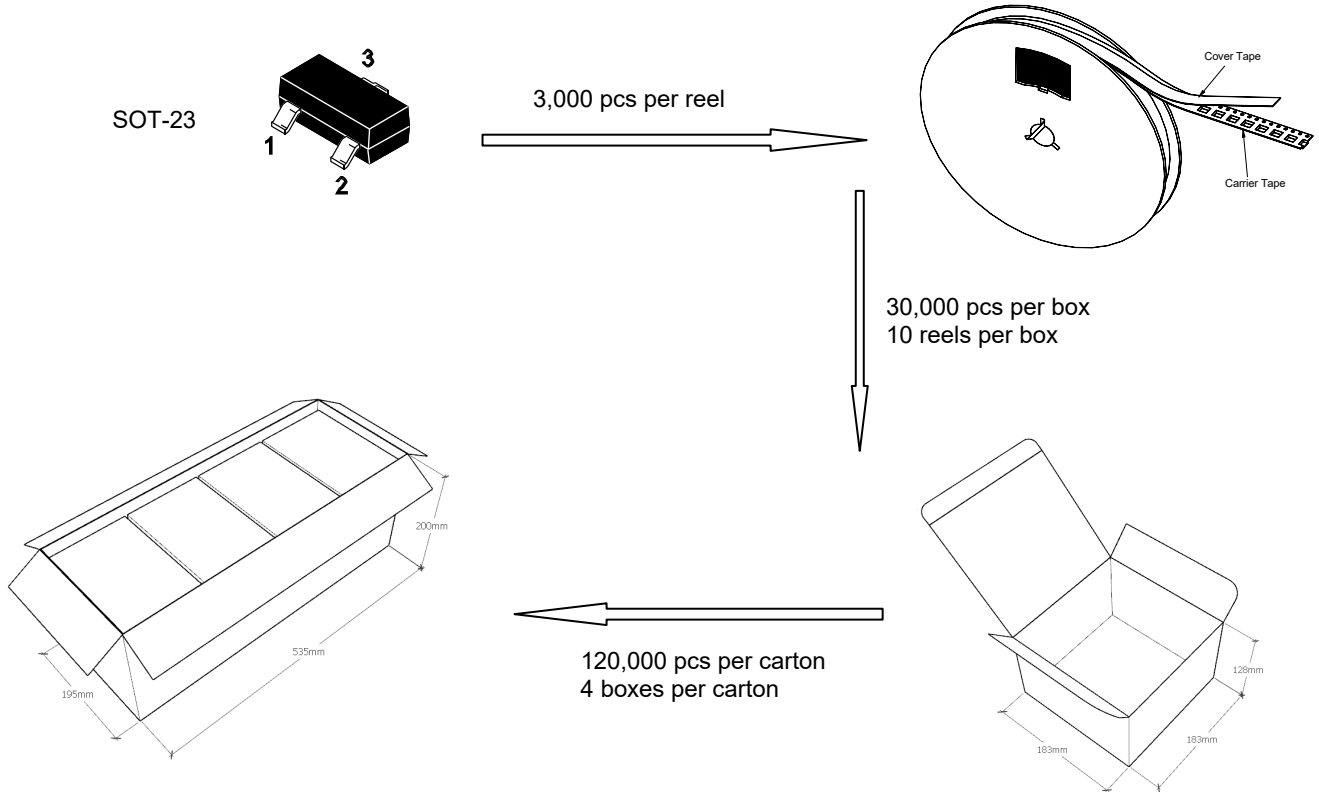
◆ Storage conditions

- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

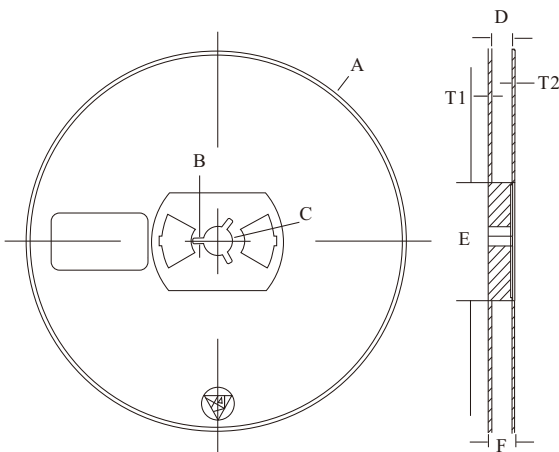


Package Specifications

- The method of packaging

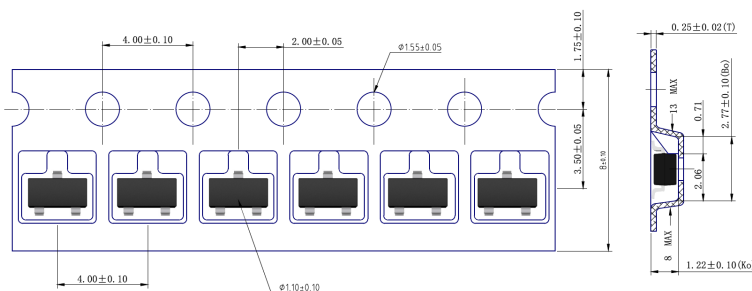


◆ **Embossed tape and reel data**



Symbol	Value (unit: mm)
A	∅ 177.8±1
B	2.7±0.2
C	∅ 13.5±0.2
E	∅ 54.5±0.2
F	12.3±0.3
D	9.6+2/-0.3
T1	1.0±0.2
T2	1.2±0.2

Reel (7")



单击下面可查看定价，库存，交付和生命周期等信息

[>>PJSEMI\(平晶微\)](#)